NSN 5962-01-135-2110

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Body Length:
1.310 inches
Body Width:
0.600 inches
Body Height:
0.052 inches
Maximum Power Dissipation Rating:
400.0 milliwatts
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Training dev 08783
Features Provided:
Hermetically sealed and programmable and expandable and wire-or outputs and w/enable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
8 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
75.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

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